

March 1997 Revised March 1999

74VHCT240A Octal Buffer/Line Driver with 3-STATE Outputs

General Description

The VHCT240A is an advanced high speed CMOS octal bus transceiver fabricated with silicon gate CMOS technology. It achieves high speed operation similar to equivalent Bipolar Schottky TTL while maintaining the CMOS low power dissipation. The VHCT240A is an inverting 3-STATE buffer having two active-LOW output enables. This device is designed to be used as 3-STATE memory address drivers, clock drivers, and bus oriented transmitter/receivers.

Protection circuits ensure that 0V to 7V can be applied to the input and output (Note 1) pins without regard to the supply voltage. These circuits prevent device destruction due to mismatched supply and input/output voltages. This device can be used to interface 5V to 3V systems and two supply systems such as battery back up.

Note 1: Outputs in OFF-State

Features

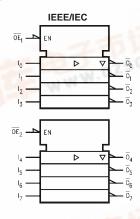
- High Speed: $t_{PD} = 5.6 \text{ ns (typ)}$ at $V_{CC} = 5V$
- Power down protection is provided on inputs and outputs
- Low power dissipation: $I_{CC} = 4 \mu A \text{ (max)} @ T_A = 25 ^{\circ}C$
- Pin and function compatible with 74HCT240

Ordering Code:

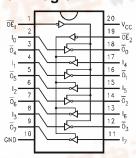
Order Number	Package Number	Package Description
74VHCT240AM	M20B	20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300 Wide
74VHCT240ASJ	M20D	20-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
74VHCT240AMTC	MTC20	20-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
74VHCT240AN	N20A	20-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300 Wide

Surface mount packages are also available on Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

Logic Symbol



Connection Diagram



Pin Descriptions

Pin Names	Description
$\overline{OE}_1, \overline{OE}_2$	3-STATE Output Enable
I ₀ -I ₇	Inputs
\overline{O}_0 – \overline{O}_7	Outputs 3-STATE Outputs



Truth Tables

Inp	uts	Outputs (Pins 12, 14, 16, 18)				
OE ₁	I _n	(PINS 12, 14, 16, 18)				
L	L	Н				
L	Н	L				
Н	Х	Z				

Inp	uts	Outputs (Pins 3, 5, 7, 9)
OE ₁	I _n	(Pins 3, 5, 7, 9)
L	L	Н
L	Н	L
H X		Z

- H HIGH Voltage Level L LOW Voltage Level X Immaterial Z High Impedance

Absolute Maximum Ratings(Note 2)

Supply Voltage (V $_{CC}$) -0.5V to +7.0V

DC Input Voltage (V_{IN}) -0.5V to +7.0V

DC Output Voltage (V_{OUT})

(Note 3) $-0.5 \text{V to V}_{CC} + 0.5 \text{V}$

 $\begin{array}{ll} \mbox{(Note 4)} & -0.5\mbox{V to } +7.0\mbox{V} \\ \mbox{Input Diode Current (I_{IK})} & -20\mbox{ mA} \\ \mbox{Output Diode Current (I_{OK}) (Note 5)} & \pm 20\mbox{ mA} \\ \mbox{DC Output Current (I_{OUT})} & \pm 25\mbox{ mA} \\ \end{array}$

DC V_{CC} /GND Current (I_{CC}) ±75 mA

-65°C to +150°C

Lead Temperature (T₁)

Storage Temperature (T_{STG})

(Soldering, 10 seconds) 260°C

Recommended Operating Conditions (Note 6)

Supply Voltage (V_{CC}) 4.5V to +5.5V

Input Voltage (V_{IN}) 0V to +5.5V

Output Voltage (V_{OUT})

 $\begin{array}{cc} \text{(Note 3)} & \text{OV to V}_{\text{CC}} \\ \text{(Note 4)} & \text{OV to +5.5V} \\ \text{Operating Temperature (T}_{\text{OPR})} & -40^{\circ}\text{C to +85}^{\circ}\text{C} \end{array}$

Input Rise and Fall Time (t_r, t_f)

 $V_{CC} = 5.0V \pm 0.5V$ 0 ns/V ~ 20 ns/V

Note 2: Absolute Maximum Ratings are values beyond which the device may be damaged or have its useful life impaired. The databook specifications should be met, without exception, to ensure that the system design is reliable over its power supply, temperature, and output/input loading variables. Fairchild does not recommend operation outside databook specifications.

Note 3: HIGH or LOW state. $I_{\mbox{OUT}}$ absolute maximum rating must be observed.

Note 4: When outputs are in OFF-State or when V_{CC} = OV. Note 5: V_{OUT} < GND, V_{OUT} > V_{CC} (Outputs Active).

Note 6: Unused inputs must be held HIGH or LOW. They may not float.

DC Electrical Characteristics

Symbol	Parameter	V _{CC} (V)	T _A = 25°C			$T_A = -40^{\circ}C \text{ to } +85^{\circ}C$		Units	Conditions	
Cymbol			Min	Тур	Max	Min	Max	Onics	Conditions	
V _{IH}	HIGH Level	4.5	2.0			2.0		V		
	Input Voltage	5.5	2.0			2.0		v		
V _{IL}	LOW Level	4.5			0.8		0.8	V		
	Input Voltage	5.5			8.0		0.8	v		
V _{OH}	HIGH Level	4.5	4.40	4.50		4.40		V	$V_{IN} = V_{IH}$ $I_{OH} = -50 \mu A$	
	Output Voltage	4.5	3.94			3.80		V	or V_{IL} $I_{OH} = -8 \text{ mA}$	
V _{OL}	LOW Level	4.5		0.0	0.1		0.1	V	$V_{IN} = V_{IH}$ $I_{OL} = 50 \mu A$	
	Output Voltage	4.5			0.36		0.44	V	or V _{IL} I _{OL} = 8 mA	
I _{OZ}	3-STATE Output	5.5			±0.25		±2.5	μА	$V_{IN} = V_{IH}$ or V_{IL}	
	Off-State Current	5.5			±0.25		±2.5		$V_{OUT} = V_{CC}$ or GND	
I _{IN}	Input Leakage	0-5.5	-5.5 ±0.1 ±1.0	μА	V _{IN} = 5.5V or GND					
	Current	0-5.5			±0.1		±1.0	μΛ		
I _{CC}	Quiescent Supply	5.5			4.0		40.0	μА	$V_{IN} = V_{CC}$ or GND	
	Current	0.0			4.0		40.0	μΑ		
I _{CCT}	Maximum I _{CC} /Input	5.5			1.35		1.50	mA	$V_{IN} = 3.4V$	
		5.5			1.55		1.50	ША	Other Input = V _{CC} or GND	
I _{OFF}	Output Leakage Current	0.0			0.5		5.0	μА	V _{OUT} = 5.5V	
	(Power Down State)	0.0			0.5		5.0	μΛ		

Noise Characteristics

								
Symbol	Parameter	V _{CC} (V)	T _A =	= 25°C	Units	Conditions		
	T drameter		Тур	Limits	Oilles			
V _{OLP} (Note 7)	Quiet Output Maximum Dynamic V _{OL}		0.9	1.1	٧	C _L = 50 pF		
V _{OLV} (Note 7)	Quiet Output Minimum Dynamic V _{OL}	5.0	-0.9	-1.1	٧	C _L = 50 pF		
V _{IHD} (Note 7)	Minimum HIGH Level Dynamic Input Voltage	5.0		2.0	V	C _L = 50 pF		
V _{ILD} (Note 7)	Maximum LOW Level Dynamic Input Voltage	5.0		0.8	V	C _L = 50 pF		

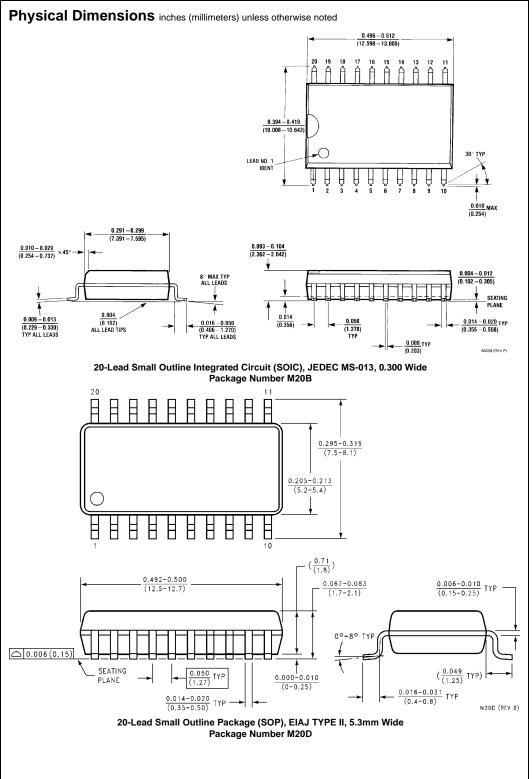
Note 7: Parameter guaranteed by design.

AC Electrical Characteristics

Symbol	Parameter Propagation Delay	V _{CC}	T _A = 25°C			$T_A = -40^\circ$	C to +85°C	Units	Conditions	
Syllibol		(V)	Min	Тур	Max	Min		Ullits	Conditions	
t _{PLH}		5.0 ± 0.5		5.6	7.8	1.0		ns		$C_{L} = 15 \text{ pF}$
t _{PHL}	Time	3.0 ± 0.3		6.1	8.8	1.0	10.0	115		$C_L = 50 pF$
t _{PZL}	3-STATE Output	5.0 ± 0.5		6.5	10.4	1.0	12.5	ns	$R_L = 1 k\Omega$	$C_{L} = 15 \text{ pF}$
t_{PZH}	Enable Time	3.0±0.5		7.3	11.4	1.0	13.5	115		$C_L = 50 pF$
t _{PLZ}	3-STATE Output	5.0 ± 0.5		7.0	11.4	1.0	13.0	ns	$R_L = 1 k\Omega$	$C_L = 50 pF$
t_{PHZ}	Disable Time	3.0 ± 0.5		7.0	11.4	1.0	13.0			
t _{OSLH}	Output to	5.0 ± 0.5			1.0		1.0	ns	(Note 8)	
toshl	Output Skew	3.0 ± 0.3			1.0		1.0	115		
C _{IN}	Input			4	10		10	pF	V _{CC} = Oper	1
	Capacitance			4	10		10	þΓ		
C _{OUT}	Output			9				pF	$V_{CC} = 5.0V$	
	Capacitance			9				рг		
C _{PD}	Power Dissipation			19				pF	(Note 9)	
Capacitance				19				þΓ		

 $\textbf{Note 8:} \ Parameter \ guaranteed \ by \ design. \ t_{OSLH} = |t_{PLH \ max} - t_{PLH \ min}|; \ t_{OSHL} = |t_{PHL \ max} - t_{PHL \ min}|$

Note 9: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load. Average operating current can be obtained by the equation: I_{CC} (opr.) = $C_{PD} * V_{CC} * f_{IN} + I_{CC}/8$ (per F/F). The total C_{PD} when n pcs. of the Octal D Flip-Flop operates can be calculated by the equation: C_{PD} (total) = 20 + 12n.

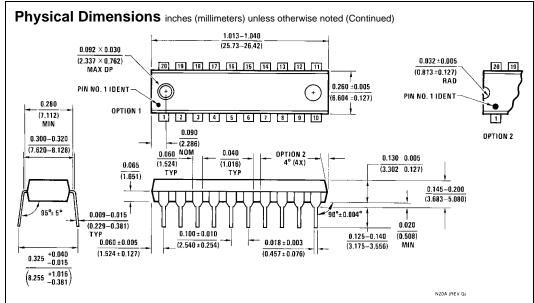


Physical Dimensions inches (millimeters) unless otherwise noted (Continued) -0.20 7.72 6,4 4.4±0.1 -B-3,2 10.42 O.2 C B A ALL LEAD TIPS PIN #1 IDENT. LAND PATTERN RECOMMENDATION SEE DETAIL A -0.90+0.15 0.09-0.20 0.1±0.05 0.65 0.19-0.30 |\Partial 0.10@|A|B\$|C\$| R0.09min GAGE PLANE DIMENSIONS ARE IN MILLIMETERS NOTES: 0.25<u>|</u> SEATING PLANE A. CONFORMS TO JEDEC REGISTRATION MID-153, VARIATION AC, REF NOTE 6, DATE 7/93. -0.6±0.1--R0.09mln B. DIMENSIONS ARE IN MILLIMETERS.

- C. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLDS FLASH, AND TIE BAR EXTRUSIONS.
- D. DIMENSIONS AND TOLERANCES PER ANSI Y14.5M, 1982.

20-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide Package Number MTC20

DETAIL A



20-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300 Wide Package Number N20A

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